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Supplementary Materials

Gas Sensing with Solar Cells: The Case of NH_3 Detection through Nanocarbon/Silicon Hybrid Heterojunctions

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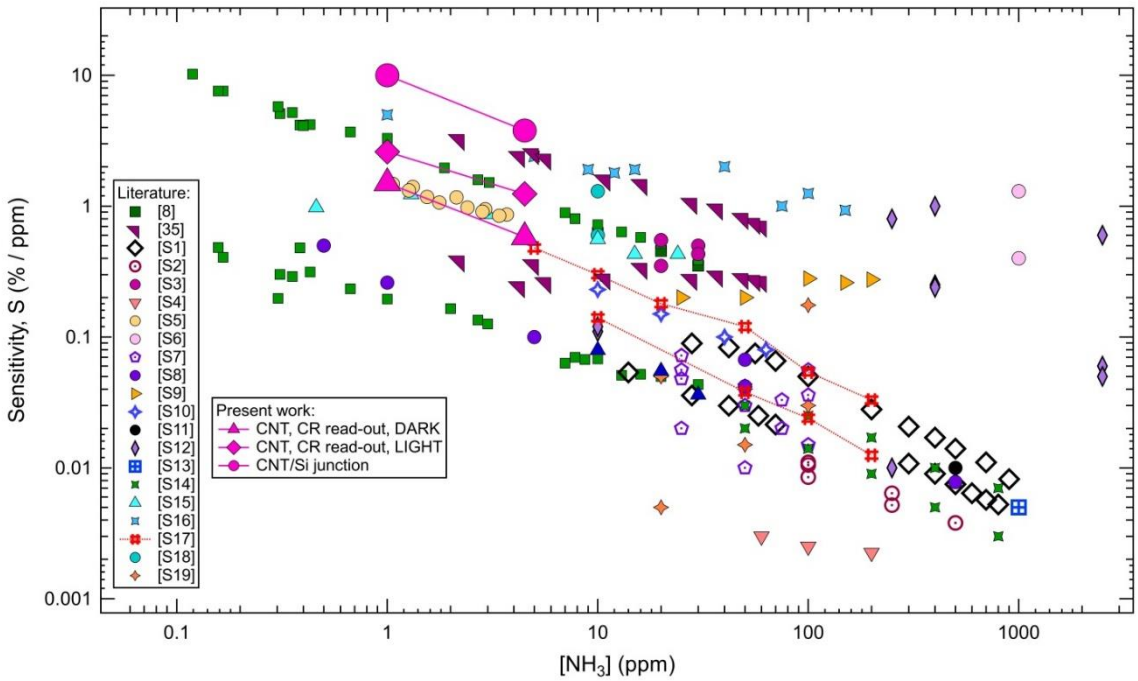

Figure S1. Benchmarking of the current CNT/Si junction sensor with respect to CNT-based chemiresistor performances (adapted from Figure 8, Nanotechnology **28** (2017) 255502 © IOP Publishing. Reproduced with permission. All rights reserved). Purple circles: CNT/Si junction; purple rhombus: chemiresistor (CR) readout under illumination; purple triangles: chemiresistor (CR) readout in dark conditions; Refs [8] and [35] refer to the main paper bibliography.

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